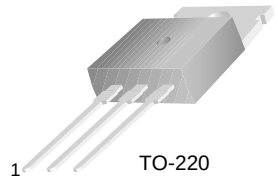
ON Semiconductor®

TIP32 / TIP32A / TIP32C
PNP Epitaxial Silicon Transistor

Features

- Medium Power Linear Switching Applications
- Complementary to TIP31 Series



TO-220

1.Base 2.Collector 3.Emitter

Ordering Information

Part Number	Top Mark	Package	Packing Method
TIP32	TIP32	TO-220 3L (Single Gauge)	Bulk
TIP32A	TIP32A	TO-220 3L (Single Gauge)	Bulk
TIP32ATU	TIP32A	TO-220 3L (Single Gauge)	Rail
TIP32C	TIP32C	TO-220 3L (Single Gauge)	Bulk
TIP32CTU	TIP32C	TO-220 3L (Single Gauge)	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_C = 25°C unless otherwise noted.

Symbol	Parameter		Value	Unit
V_{CBO}	Collector-Base Voltage	TIP32	-40	V
		TIP32A	-60	
		TIP32C	-100	
V_{CEO}	Collector-Emitter Voltage	TIP32	-40	V
		TIP32A	-60	
		TIP32C	-100	
V_{EBO}	Emitter-Base Voltage		-5	V
I_C	Collector Current (DC)		-3	A
I_{CP}	Collector Current (Pulse)		-5	A
I_B	Base Current		-3	A
T_J	Junction Temperature		150	°C
T_{STG}	Storage Temperature Range		-65 to 150	°C

November-2017,Rev. 2

Publication Order Number:
TIP32C/D

Thermal Characteristics

Values are at T_C = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
P_C	Collector Dissipation (T_A = 25°C)	2	W
	Collector Dissipation (T_C = 25°C)	40	

Electrical Characteristics

Values are at T_C = 25°C unless otherwise noted.

Symbol	Parameter		Conditions	Min.	Max.	Unit
V_{CEO}(sus)	Collector-Emitter Sustaining Voltage(1)	TIP32	I_C = -30 mA, I_B = 0	-40		V
		TIP32A		-60		
		TIP32C		-100		
I_{CEO}	Collector Cut-Off Current	TIP32 / TIP32A	V_{CE} = -30 V, I_B = 0		-0.3	mA
		TIP32C	V_{CE} = -60 V, I_B = 0		-0.3	
I_{CES}	Collector Cut-Off Current	TIP32	V_{CE} = -40 V, V_{EB} = 0		-200	µA
		TIP32A	V_{CE} = -60 V, V_{EB} = 0		-200	
		TIP32C	V_{CE} = -100 V, V_{EB} = 0		-200	
I_{EBO}	Emitter Cut-Off Current		V_{EB} = -5 V, I_C = 0		-1	mA
h_{FE}	DC Current Gain(1)		V_{CE} = -4 V, I_C = -1 A	25		
			V_{CE} = -4 V, I_C =- 3 A	10	50	
V_{CE}(sat)	Collector-Emitter Saturation Voltage(1)		I_C = -3 A, I_B = -375 mA		-1.2	V
V_{BE}(on)	Base-Emitter On Voltage(1)		V_{CE} = -4 V, I_C = -3 A		-1.8	V
f_T	Current Gain Bandwidth Product		V_{CE} = -10 V, I_C = -500 mA, f = 1 MHz	3.0		MHz

Note:

1. Pulse test: pw ≤ 300 µs, duty cycle ≤ 2%.

Typical Performance Characteristics

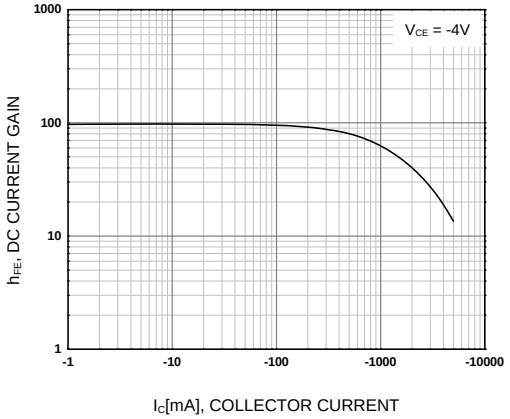


Figure 1. DC Current Gain

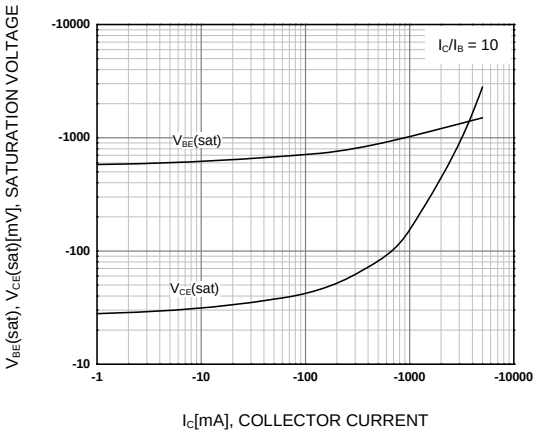


Figure 2. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

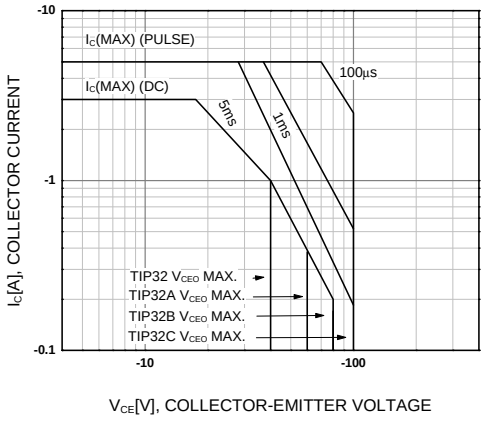


Figure 3. Safe Operating Area

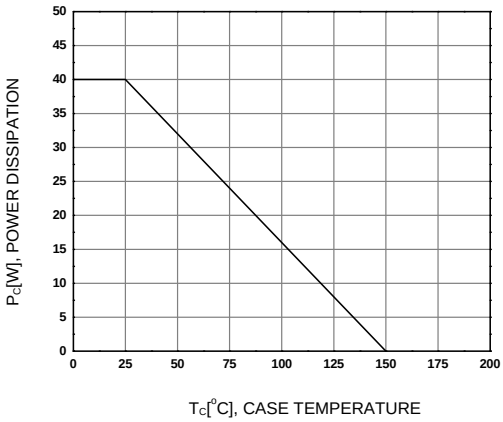


Figure 4. Power Derating

Physical Dimensions

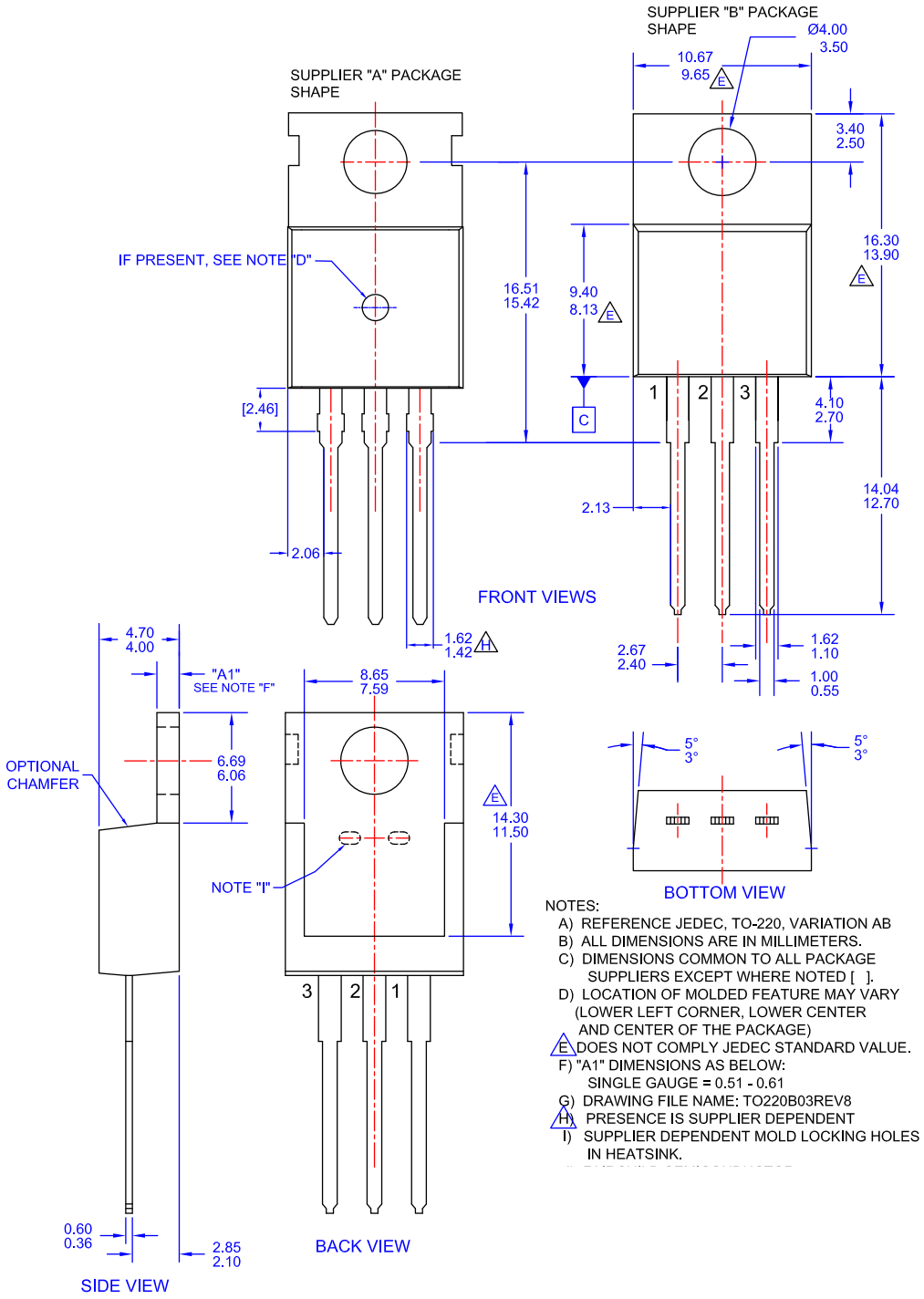


Figure 5. TO-220, MOLDED, 3LEAD, JEDEC VARIATION AB

PUBLICATION ORDERING INFORMATION

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